



**DMN2991UT** 

#### N-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BV <sub>DSS</sub>	Rds(on)	<b>І</b> р Т <sub>А</sub> = +25°С
	3Ω @ V <sub>GS</sub> = 4.5V	0.3A
20V	4Ω @ V <sub>GS</sub> = 2.5V	0.26A
	6Ω @ V <sub>GS</sub> = 1.8V	0.21A

### **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

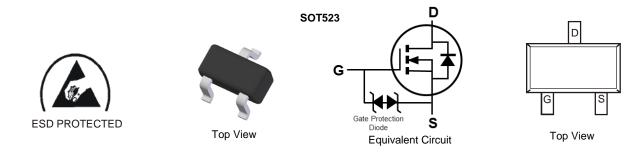
- DC-DC Converters
- Load Switch
- Power Management Functions

## **Features and Benefits**

- Low On-Resistance
- Very Low Gate Threshold Voltage, 1.0V Max
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/guality/product-definitions/</u>

### **Mechanical Data**

- Case: SOT523
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 3
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)



## Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2991UT-7	SOT523	3000/Tape & Reel
DMN2991UT-13	SOT523	10000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**

Notes:

SOT523												
			BE5	YM	BE5 = Product Type Marking Code YM = Date Code Marking $Y \text{ or } \overline{Y} = Year (ex: H = 2020)$ M = Month (ex: 9 = September)							
Date Code Key												
Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	Н		J	K	L	М	N	0	Р	R	S	Т
Month	lan	Fab	Mar	Amr	May	lum	Int	Aug	Sep	Oct	Nov	Dec
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	001	NOV	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



# Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			Vdss	20	V
Gate-Source Voltage			V <sub>GSS</sub>	±10	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = 4.5V	Steady State	TA = +25°C TA = +75°C	lD	0.3 0.24	A
Maximum Continuous Body Diode Forward Current (Note 6)			ls	0.3	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			Ідм	1.4	A

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	PD	0.28	W	
Thermal Resistance, Junction to Ambient (Note 5)	Reja	439	°C/W	
Total Power Dissipation (Note 6)		PD	0.43	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	291	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

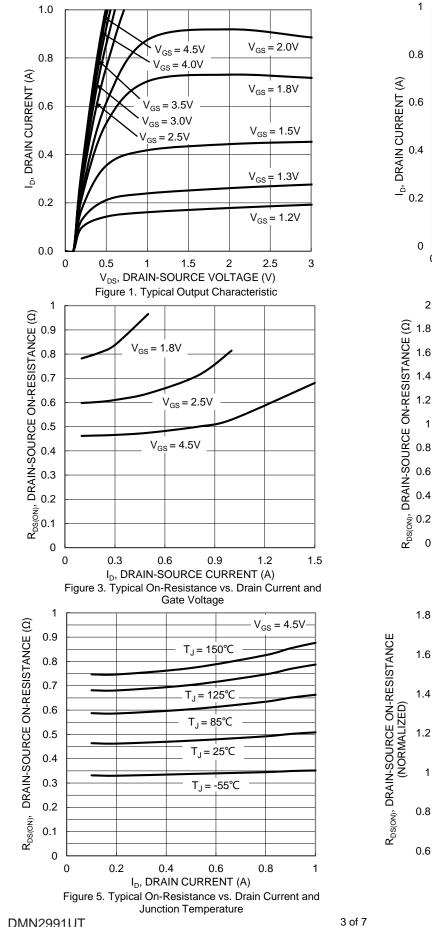
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)			51			
Drain-Source Breakdown Voltage	BVDSS	20	—	—	V	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250µA
Zero Gate Voltage Drain Current	IDSS	_	—	1	μA	V <sub>DS</sub> = 16V, V <sub>GS</sub> = 0V
Gate-Source Leakage	I <sub>GSS</sub>	_	—	±10	μA	$V_{GS} = \pm 5V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(th)	0.5	—	1.0	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$
		_	0.4	3.0		$V_{GS} = 4.5V, I_{D} = 100mA$
Static Drain-Source On-Resistance	Descent	_	0.6	4.0	Ω	$V_{GS} = 2.5V, I_{D} = 50mA$
	RDS(ON)	_	0.8	6.0	12	$V_{GS} = 1.8V, I_{D} = 20mA$
		_	1.0	10.0		V <sub>GS</sub> = 1.5V, I <sub>D</sub> = 10mA
Diode Forward Voltage	V <sub>SD</sub>	_	0.8	1.0	V	$V_{GS} = 0V, I_{S} = 150mA$
DYNAMIC CHARACTERISTICS (Note 8)						-
Input Capacitance	Ciss	_	21.5	—	pF	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V, f = 1.0MHz
Output Capacitance	Coss	_	4.9	—	pF	
Reverse Transfer Capacitance	Crss	_	3.7	—	pF	
Gate Resistance	Rg	_	0.94	—	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1.0MHz$
Total Gate Charge	Qg	_	0.35	—	nC	
Gate-Source Charge	Qgs	—	0.07	—	nC	VGS = 4.5V, VDS = 10V, ID = 250mA
Gate-Drain Charge	Q <sub>gd</sub>	—	0.08	—	nC	1D = 23011A
Turn-On Delay Time	tD(ON)	—	5.6	—	ns	
Turn-On Rise Time	tR	—	4.9	—	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$
Turn-Off Delay Time	t <sub>D(OFF)</sub>	—	60.6	—	ns	$R_{L} = 47\Omega, R_{g} = 10\Omega,$
Turn-Off Fall Time	tF	_	27.6	—	ns	I <sub>D</sub> = 200mA

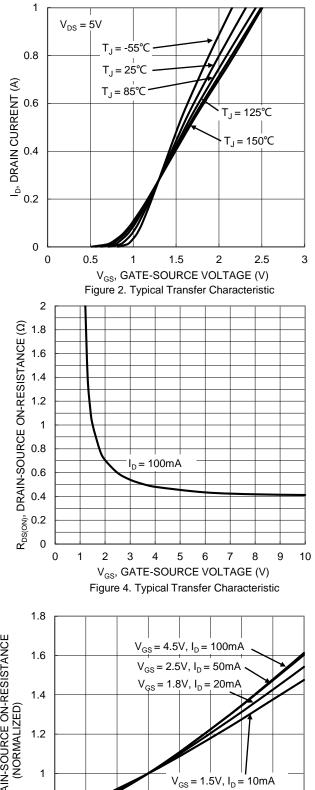
Notes: 5. Device mounted on FR-4 substrate PC board, with minimum recommended pad layout.

Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.



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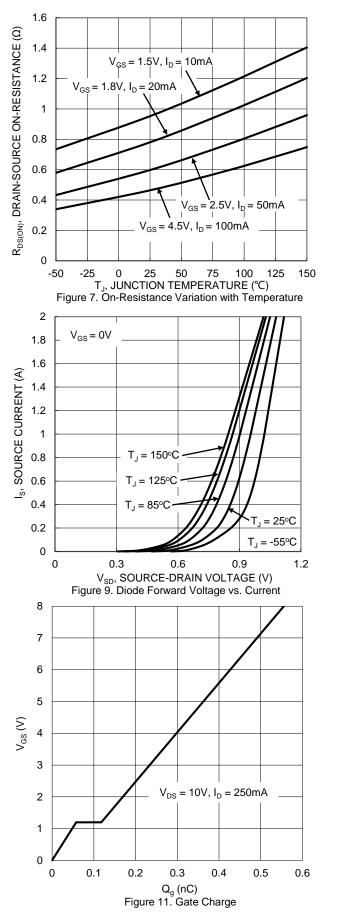


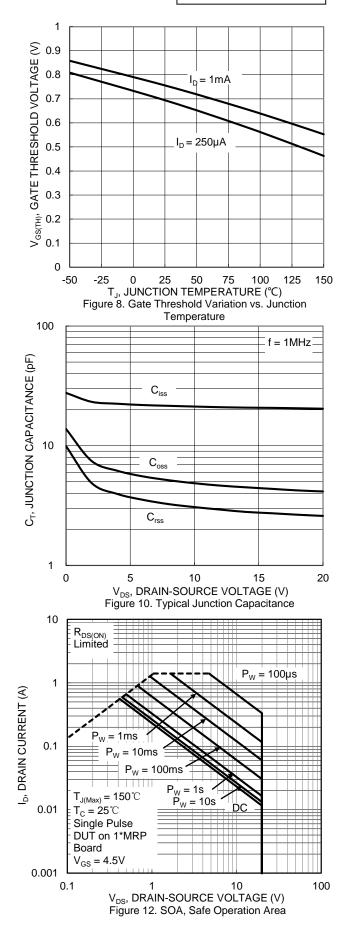
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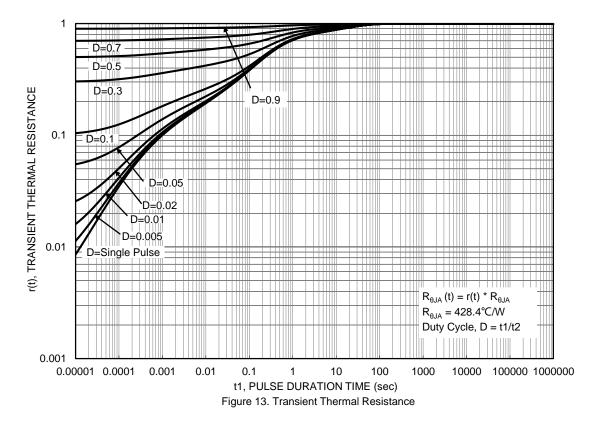






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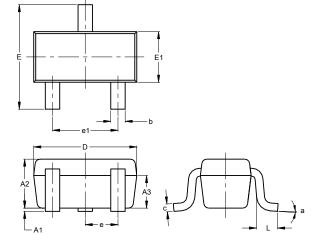


# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT523

SOT523



SOT523							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.60	0.80	0.75				
A3	0.45	0.65	0.50				
b	0.15	0.30	0.22				
С	0.10	0.20	0.12				
D	1.50	1.70	1.60				
Е	1.45	1.75	1.60				
E1	0.75	0.85	0.80				
е		0.50 BS	С				
e1	0.90	1.10	1.00				
L	0.20	0.40	0.33				
а	0°		8°				
All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

 $\begin{array}{c|c} & & & \\ & & & \\$ 

Dimensions	Value (in mm)
C	1.29
Х	0.40
X1	0.70

0.51

1.80

Υ

Y1



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